

Effect of on-site Coulomb interaction (U) on the electronic and magnetic properties of Fe_2MnSi , Fe_2MnAl and Co_2MnGe

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Abstract. The electronic band structures, density of states plots and magnetic moments of Fe_2MnSi , Fe_2MnAl , and Co_2MnGe are studied by using the first principles calculations. The FM solutions using LSDA without U show the presence of half-metallic ferromagnetic (HFM) ground state in Fe_2MnSi , whereas the ground state of Fe_2MnAl is found to be metallic. In both compounds the maximum contribution to the total magnetic moment is from the Mn atom, while the Fe atom contributes very less. The electronic structures and magnetic moments of Fe-based compounds affected significantly by U , whereas its effect is very less on Co_2MnGe . The magnetic moment of Fe atom in Fe_2MnSi (Fe_2MnAl), increased by $\sim 70\%$ ($\sim 75\%$) and in Mn atom it decreases by $\sim 50\%$ ($\sim 70\%$) when the value of U is increased from 1 to 5 eV. The Hund's like exchange interactions are increasing in Fe atom while decreasing in Mn atom with increase in U . The Fe and Mn moments are ferromagnetically coupled in Fe_2MnSi for all values of U , whereas in Fe_2MnAl they coupled antiferromagnetically below $U = 2$ eV and ferromagnetically above it. Above $U = 2$ eV the metallic ground state of Fe_2MnAl changes to semiconducting ground state and the ferromagnetic coupling between Fe and Mn atoms appears to be responsible for this.

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1. Introduction

After the discovery of half-metallic ferromagnetism in half-Heusler alloy NiMnSb by de Groot et al.[1] many of the compounds were found to be half-metallic in different experimental [2, 3] and theoretical studies[4, 5, 6, 7, 8, 9, 10]. The half-metallic ferromagnets (HMFs) have band gap at the Fermi level (E_F) in one spin channel while the other spin channel is strongly metallic. These materials show a complete spin polarization of the conduction electrons at the E_F . Because of their exceptional band structures at the E_F , these materials are of great interest from theoretical and applications point of view. Co containing full-Heusler alloys were firstly proposed by Ishida et al.[6] and were synthesised by Webster[11]. Fe_2MnZ type Heusler alloys have also been proposed to show half-metallic ferromagnetism by Fujii et al.[7]. In the family of Fe based Heusler alloys only Fe_2MnSi [7] and Fe_2CrZ ($Z = \text{Si, Ge, Sn}$) [12] were predicted to be half-metallic ferromagnets theoretically. Fe_2MnSi is a ferromagnetic material with a Curie temperature of 214 K and transforms at 69 K to the low temperature phase with smaller spontaneous magnetization [13]. The total magnetic moment of Fe_2MnSi obtained by magnetization measurements is $2.1 \mu_B/\text{f.u.}$ (f.u. $\equiv$ formula unit) at 4.2 K [14] which is smaller than the calculated moment of $3.0 \mu_B/\text{f.u.}$ [15, 16]. Fe_2MnAl on the other hand is not a half-metallic as there exist slight density of states at the E_F for minority spin channel [7].

It is well known that the local spin density approximation (LSDA) and the generalized gradient approximation (GGA) schemes for the exchange-correlation potential are not sufficient to describe the electronic structure and magnetism of some Heusler alloys like Co_2FeSi [17, 18]. Such strongly correlated systems which contain atoms with open d or f shells, can be treated by adding on-site Coulomb interaction (U) term as modification to LSDA i.e. by using LSDA + U approach [19]. The LSDA + U method accounts an orbital-dependent on-site electron-electron Coulomb interaction which is not included in the pure LDA or GGA. Rai et al.[20, 21] have studied some Co based Heusler alloys and reported the increase in band gap, hybridization of d - d orbitals as well as d - p orbitals when on-site Coulomb interaction is added to LSDA approach. They have also concluded that some Co-based Heusler alloys show half-metallic character when are treated with LSDA + U . It is well known that the systems in which there exist the density of states (DOS) at the Fermi energy for one spin, the on-site Coulomb interaction (U) may bring a drastic change into their electronic and magnetic properties [22]. As the electron-electron correlation plays an important role in the Heusler compounds so it can be expected that it will also affect the Fe-based Heusler alloys.

In the present work we have employed the full-potential linearized augmented-plane wave methods to compute the electronic and magnetic properties of three full-Heusler alloys viz. Fe_2MnSi , Fe_2MnAl , and Co_2MnGe . The electronic structures in the FM solutions without U show that Fe_2MnSi is half-metallic compound whereas Fe_2MnAl is metallic. The large effect of U is observed on the electronic structures and magnetic

moments of Fe-based compounds whereas on Co_2MnGe compound its effect is negligibly small. The magnetic moment of Fe atom increases with U and in the Mn atom it decreases with U . The magnetic moments of Fe and Mn atoms are found to be coupled ferromagnetically in Fe_2MnSi for all values of U , whereas in Fe_2MnAl they coupled antiferromagnetically below $U = 2$ eV and ferromagnetically above it. The ground state of Fe-based compounds remains half-metallic for all values of U , whereas it changes from metallic to semiconductor in Fe_2MnAl after $U = 2$ eV. Also the ferromagnetic coupling between Fe and Mn atom is found to be responsible for the presence of semiconducting ground state in this compound.

2. Computational details and Crystal structure

The electronic and magnetic properties of Fe_2MnSi , Fe_2MnAl and Co_2MnGe were calculated by using the full-potential linearized augmented plane-wave (FP-LAPW) method within the density functional theory (DFT) implemented in WIEN2k code[23]. The local spin density approximation (LSDA) of Perdew and Wang [24] was employed for exchange-correlation energy of electrons. The effect of on-site Coulomb interaction (U) under LSDA + U [19] formulation of the DFT was also considered in the calculations. The around-the-mean-field (AMF) version of the LSDA+ U [19] method was employed to account for the double-counting correction terms in the energy functional. The effective Coulomb-exchange interaction U_{eff} is given by $(U - J)$, where U and J are the Coulomb and exchange parameter. The value of U was varied from 1 to 5 eV and J was kept fixed to 0 eV, therefor U_{eff} was equal to U in our calculations. The values of muffin-tin radii used in the calculations were 2.2 Bohr for Fe, Mn, Si and Al atoms. The maximum l value (l_{max}) for the expansion of wave function in spherical harmonics inside the atomic spheres was equal to 10. For convergence of energy eigenvalues the wave function in the interstitial regions were expanded in plane waves with cutoff $R_{mt}K_{max} = 8$, where R_{mt} is the smallest atomic sphere radius and K_{max} is largest k vector in the plane wave expansion. The electronic and magnetic properties of these compounds were calculated by using the experimental lattice parameters. The self consistent iteration was repeated until calculated total energy/cell and charge/cell of the systems converge to less than 10^{-4} Ry and 0.001e, respectively.

All these compounds belong to the family of full Heusler alloys and crystallizes in $L2_1$ crystal structure with space group $Fm-3m$. These compounds have composition X_2YZ , where X and Y are transition metals and Z is the main groups element. X atoms (Fe and Co) are placed at Wyckoff position 8c ($1/4, 1/4, 1/4$). Y atoms (Mn) and Z atoms (Si, Al and Ge) are located at Wyckoff position 4a (0, 0, 0) and 4b ($1/2, 1/2, 1/2$), respectively [25, 26].

3. Results and discussions

3.1. Paramagnetic Phase

The dispersion curves of Fe_2MnSi and Fe_2MnAl along the high symmetry directions of the first Brillouin zone are presented in Fig. 1(a and b). In the dispersion curve of Fe_2MnSi , the bands labeled by 1, 2 and 3 are lying above the E_F , bands 4, 5, 6 and 7 are crossing it at 14 different k-points and band 8 is lying below it. Around W-point, bands 4-7 are concentrated in the energy range of about -0.2 to 0.2 eV. The total energy of the system can be minimized if there will be shifting of these bands and this shifting may lead to the FM ground state for this compound. From Fig. 1(b) it is clear that in Fe_2MnAl the bands labeled by 1-5 are lying above the E_F , bands 6 and 7 which are crossing the E_F at 10 different k-points and band 8 is lying just below it. Bands 4-7 are concentrated around the W-point in the energy range of about -0.2 to 0.2 eV. Therefore here also one can expect that shifting of these bands will minimize the total energy of the system which may lead to the ferromagnetic ground state in the compounds. These results are consistent with our earlier reported results for the paramagnetic phase of Co_2MnGe [27].

The total and partial density of states plots of Fe_2MnSi and Fe_2MnAl are presented in Fig. 2 and Fig. 3, respectively. From total density of states plots (TDOS) (Fig. 2(a) and 3(a)) it is clear that there is very large density of states of about 6 states/eV/f.u. (f.u. $\equiv$ formula unit) at E_F for both the spins. According to the Stoner theory the large value of TDOS may be considered as the indication of the ferromagnetic ground states in the compounds[28, 27]. The antibonding bands are extended upto 0.4 eV and 0.3 eV below the E_F for Fe_2MnSi and Fe_2MnAl , respectively. As per Stoner theory the total energy of the systems will be minimized if there is a shifting in spin-up and spin-down bands by ~ 0.4 eV and 0.3 eV below and above the E_F for Fe_2MnSi and Fe_2MnAl , respectively. This may be responsible for the half-metallic FM ground state in the compounds as observed in the case of Co_2MnGe [27]. Also the total energies of FM phase of Fe_2MnSi and Fe_2MnAl are about 0.77 eV and 0.54 eV less than PM phase, which further confirm that both compounds should have FM ground states. The partial density of states (PDOS) plots for Fe, Mn and Si atoms of Fe_2MnSi are presented in Fig. 2(b-d). From Fig. 2(b) it is evident that the PDOS of Fe atom at E_F is mainly contributed by t_{2g} and e_g states with contribution of about 0.3 states/eV/atom and about 2.0 states/eV/atom, respectively for both spin channels. The PDOS of Mn atom is shown in Fig. 2(c) and in both spin channels the contribution from t_{2g} and e_g is ~ 1 states/eV/atom and ~ 1.6 states/eV/atom, respectively. The PDOS of Si atom (Fig. 2(d)) show that the occupancy of $3s$ and $3p$ orbitals at E_F is very small, which can be neglected. The PDOS plots for Fe, Mn and Al atoms of Fe_2MnAl are shown in Fig. 3(b-d). It is clear from Fig. 3(b) that the contribution of t_{2g} is ~ 0.3 states/eV/atom and e_g is ~ 1 states/eV/atom at E_F for both spin channels. In the PDOS of Mn (Fig. 3(c)) the occupancy of t_{2g} at E_F is ~ 0.7 states/eV/atom and e_g at E_F is ~ 2.0 states/eV/atom. From PDOS plot of Al atom (Fig. 3(d)) it is evident that there is negligibly small

contribution from $3s$ and $3p$ orbitals at E_F . It is also clear from these figures that t_{2g} and e_g have main contribution to the total DOS at E_F for Fe_2MnSi and Fe_2MnAl . The e_g state has the largest contribution to the TDOS of both compounds at E_F .

3.2. Ferromagnetic Phase

The spin resolved dispersion curves of Fe_2MnSi and Fe_2MnAl along the high symmetry directions of the first Brillouin zone are shown in Fig. 4. From the dispersion curve shown in Fig. 4(a) it is clear that Fe_2MnSi is metallic for spin-up channel. Bands labeled by 1 and 2 are lying just above the E_F , bands 3 and 4 are crossing the E_F at 7 different k-points and bands 5-7 are lying just below it. Fig. 4(b) shows that this compound behave as semiconductor for down spin channel and there exist an indirect gap of about 0.44 eV from Γ to X-direction. The computed value of indirect band gap using LSDA is less than the reported value [29]. This compound is found to be half-metallic similar to the previous studies [7, 30]. Bands labeled by 1-6 have shifted into the conduction band while bands 7 and 8 have shifted into the valence band and thus there is presence of ferromagnetic ground state in this compound as stated earlier. From the dispersion curves shown in Fig. 4(c and d), it is very clear that Fe_2MnAl is metallic in nature. In the spin-up channels bands 1-4 are lying above the E_F and bands 5-8 are crossing it at 8 different k-points. In down spin channel bands 1-7 are lying above E_F and only one band, labelled by 8 is crossing it at two different k-points. Thus there exist a slight density of states at E_F in the spin-dn channel and making this compound metallic in nature. There is almost flat conduction band along Γ to X direction in the down spin channel of both compounds and this can be responsible for large value of effective masses of these compounds.

Total and partial DOS plots of Fe_2MnSi for FM solution are shown in Fig. 5. From Fig. 5(a), it is clear that spin-up channel is occupied at E_F with occupancy of about 5 states/eV/f.u. whereas spin-down channel is unoccupied. Thus this compound behave as metal for majority spin states and semiconductor for minority spin states. After comparing Fig. 2(a) and 5(a), one can conclude that TDOS shifts towards lower energy in spin-up channel whereas, in spin-down channel it shifts towards higher energy. Because of this shift there is creation of band gap in the minority spin channel as is observed in Co_2MnGe . This band shift appears to be responsible for the presence of FM ground state in this compound. However, in this compound the shift in TDOS is very small in comparison to rigid shift observed in spin-up channel of Co_2MnGe [27]. Also the value of TDOS at E_F is very large in comparison to TDOS of Co_2MnGe studied earlier and one can expect very large effect of on-site Coulomb interaction (U) on such systems. From the PDOS of Fe atom (Fig. 5(b)) it is clear that t_{2g} (~ 0.5 states/eV/atom) and e_g (~ 1.4 states/eV/atom) states have main contribution at E_F for spin-up channel while the minority spin channel is empty. Near the E_F in spin-dn channel, the valence band maximum has main contribution from t_{2g} and conduction band minimum is contributed by e_g states. The PDOS of Mn atom is presented in Fig. 5(c) and it is clear from

this plot that t_{2g} bands have occupation of ~ 1.0 states/eV/atom with negligibly small contribution from e_g band at E_F for spin-up channel. The e_g band of Mn atom has shifted towards lower energy with no contribution at the E_F . The PDOS of Si atom (Fig. 5(d)) shows negligibly small contribution from $3s$ and $3p$ orbitals.

The total and partial density of states plots of spin-up and spin-down channels for Fe_2MnAl are shown in Fig. 6. The spin-up channel of Fig. 6(a) shows that total density of states at E_F is ~ 1 states/eV/f.u. and spin-down channel show very small (~ 0.1 states/eV/f.u.) density of states at E_F . On comparing Fig. 3(a) and 6(a) one can find that there is no rigid shifting of bands rather there is splitting of bands at E_F , which we have not observed in Co_2MnGe and Fe_2MnSi . The PDOS of Fe, Mn and Al atoms for both spin channels are shown in Fig. 6(b-d). From Figs. 3(b) and 6(b) it is clear that there is no rigid shift in band as per Stoner theory as is observed in Co_2MnGe [27]. The e_g states split in such a way that there exists a minimum at E_F with contribution of ~ 0.3 states/eV/atom and 0.1 states/eV/atom, from t_{2g} and e_g bands, respectively. This minimum is responsible for the existence of the pseudo gap. In the minority spin channel the valence band maximum has mainly t_{2g} character and conduction band minimum has e_g character. This compound show metallic nature for down spin also because of very small contribution from t_{2g} bands at E_F . In Fig. 6(c) the PDOS for Mn t_{2g} and e_g bands are shown. The spin-up channel of PDOS of Mn atom is contributed by t_{2g} state (~ 0.2 states/eV/atom) with negligibly small contribution from e_g state at E_F . It is evident from Fig. 6(d) that in PDOS of Al atom there is negligibly small contribution of $3s$ and $3p$ orbitals.

The total magnetic moment per formula unit for Fe_2MnSi is $3.0 \mu_B$ with contribution from Fe, Mn, Si and interstitial region is 0.22 , 2.52 , -0.01 and $0.042 \mu_B$, respectively. The similar value of total magnetic moment is also predicted theoretically in [31, 16], whereas the experimental results [32, 33] gave a saturation magnetic moment less than this value. This may be due to the reason that it is difficult to obtain the pure phases experimentally. The Mn atom coupled ferromagnetically with Fe atom as is found by Galanakis et al.[31]. The magnetic moment of Si is very small and it is coupled antiferromagnetically with Fe and Mn atoms. The total magnetic moment per formula unit for Fe_2MnAl is $2.0 \mu_B$ and contribution from Fe, Mn, Al and interstitial region is -0.23 , 2.44 , -0.008 and $0.05 \mu_B$, respectively. The calculated value of the total magnetic moment matches with earlier reported value [31]. The Mn atom coupled antiferromagnetically with Fe atom in this compound. By using the full-potential screened Korringa-Kohn-Rostoker (FSKKR) Greens function method in conjunction with the local spin density approximation Galanakis et al.[31] have also found similar results. But Fujii et al. [7] have observed ferromagnetic coupling between Fe and Mn atoms which is contradictory to our results. The magnetic moment of Al is very small but it is coupled ferromagnetically with Fe atom and antiferromagnetically with Mn atom. The Mn atom carries the largest magnetic moment in all these compounds, while the Fe atom of Fe_2MnSi and Fe_2MnAl carry the modest magnetic moment which is in agreement with the earlier reported results [34].

3.3. Effect of on-site Coulomb interaction (U)

From the study of electronic structure of Fe_2MnSi it is clear that for spin-up channel there is very large density of states at E_F and spin-down channel is empty. The electronic structure of Fe_2MnAl show comparatively small value of TDOS from $3d$ bands at E_F for both spin channels. It is well known that $3d$ bands are less dispersive therefore on-site Coulomb interaction can have very large effect on the electronic and magnetic properties of such compounds. The LSDA+ U method may bring a drastic change on the magnetic properties and electronic properties of these compounds. So we have study the effect of U varying from 1 to 5 eV on the magnetic moment and electronic structure of these compounds along with previously studied Co_2MnGe compound [27].

Firstly, we discuss the effect of U on the magnetic moments of all these compounds. The total number of $3d$ electrons in both spin channels and local magnetic moments in the presence of U are presented in Table 1 for Fe_2MnSi , Fe_2MnAl and Co_2MnGe . It is clear from Table that in Fe_2MnSi , the number of $3d$ electrons of Fe atom in up spin channel increases while that of down spin channel decreases with U . However the total number of electrons remains fixed to the value ~ 6.1 . The local magnetic moment of Fe atom is found to increase with increasing the value of U . The magnetic moment increases from $0.29 \mu_B$ at $U = 1$ eV to $0.87 \mu_B$ at $U = 5$ eV. In Mn atom, the total number of $3d$ electrons in spin-up channel decreases and spin-dn channel increases with U in such a way that total number of $3d$ electrons remains fixed to the value ~ 4.9 . Also the magnetic moment of Mn atom decreases from $2.41 \mu_B$ at $U = 1$ eV to $1.29 \mu_B$ at $U = 5$ eV. The above results suggest that the Hund's like exchange interactions between Fe $3d$ electrons are increasing and that of Mn $3d$ electrons decreasing with increase in U .

In Fe_2MnAl , also the number of electrons of Fe (Mn) atom in up spin channel increases (decreases) while that of down spin channel decrease (increases) with U . The value of local magnetic moment of Fe atom also goes on increasing with increasing the value of U . The value of magnetic moment increases from $-0.14 \mu_B$ at $U = 1$ eV to $0.55 \mu_B$ at $U = 5$ eV. There is also a very anomalous effect of U on the magnetic moment of Fe atom, as the magnetic moment changes its sign after $U = 2$ eV and coupled ferromagnetically with Mn atom. On the other hand the magnetic moment of Mn decreases from $2.24 \mu_B$ at $U = 1$ eV to $0.77 \mu_B$ at $U = 5$ eV. At $U = 2$ eV, the magnetic moment of Fe atom become almost zero and the total magnetic moment is contributed only by the Mn atom. In the Fe atom the Hund's like exchange interactions are also found to increase with U while in Mn atom decrease with U . In comparison to Fe_2MnSi the effect of U on the magnetic properties of Fe_2MnAl compound is found to be more.

The on-site Coulomb interactions are affecting above two compounds drastically but we have observed no drastic effect on the magnetic moment of Co_2MnGe . In this compounds the number of electrons in spin-up and spin-dn channels are no changing significantly with U . The magnetic moment of Co atom increases slightly from $1.07 \mu_B$

at $U = 1$ eV to $1.15 \mu_B$ at $U = 5$ eV. The magnetic moment of Mn atom decreases from $2.80 \mu_B$ at $U = 1$ eV to $2.61 \mu_B$ at $U = 5$ eV.

The value of U is affecting the magnetic properties of these compounds although it has very less effect on Co_2MnGe . Therefore we have also studied the electronic structures of all these compounds in the presence of U . The total and partial DOS of Fe_2MnSi , Fe_2MnAl and Co_2MnGe are presented in Fig. 7-9 only for two selected values of U i.e. $U = 2$ and 4 eV .

The spin-up channel of Fig. 7(a) shows that the TDOS at E_F decrease very slowly with U and there exists a gap at E_F in down spin channel. The value of band gap in spin-up channel increases from ~ 0.8 eV at $U = 2$ eV to ~ 0.9 eV at $U = 4$ eV. TDOS in the spin-up and spin-dn channels shifts towards the lower energy as the value of U is increased from 2 eV to 4 eV. The PDOS of Fe atom is presented in Fig. 7(b) and it is evident from figure that for these two values U , e_g and t_{2g} states are contributing to the TDOS at E_F with more contribution from e_g states. Also the contribution from t_{2g} and e_g states at E_F decreases from ~ 0.45 states/eV/atom at $U = 2$ eV to ~ 0.27 states/eV/atom at $U = 4$ eV and ~ 1.7 states/eV/atom at $U = 2$ eV to ~ 1.0 states/eV/atom at $U = 4$ eV, respectively. The contribution from both these states decrease with U and PDOS appears to shift towards lower energy in the both spin channels. The PDOS of Mn (Fig. 7(c)) at E_F is occupied by t_{2g} states with negligibly small contribution from e_g states. Also the occupancy of t_{2g} states decreases very slowly with U and t_{2g} and e_g states shift towards lower energy in spin-up channel. In the down spin channel the t_{2g} states also shift towards lower energy while, e_g states shift towards higher energy. The PDOS of Si atom has negligibly small contribution from $3s$ and $3p$ orbitals for these values of U .

The TDOS of Fe_2MnAl for $U = 2$ eV and 4 eV are shown in Fig. 8(a). For $U = 2$ eV, the soft gap is appearing in the spin-up channel and when value of U is increased this compound become semiconductor with band gap of ~ 0.7 eV. In the spin-dn channel the band gap does not change significantly with U . This is also observed in magnetic moment calculations, where at $U = 2$ eV, the magnetic moment of Fe atom become almost zero and for $U = 4$ eV the value of magnetic moment is positive. The TDOS for both the spin channels shift towards higher energy at $U = 4$ eV. The PDOS of Fe, Mn and Al atoms shown in Fig. 8(b-d) for $U = 2$ eV and $U = 4$ eV. From PDOS of Fe atom it is clear that t_{2g} and e_g states shifts towards higher energy for both the spin channels. The PDOS of Mn atom show that in spin-up channel shifting of t_{2g} states is dominating and in spin-dn channel shifting of e_g states is more dominating. Also shifting is taking place at higher rate in the conduction band. The PDOS of Al atom has also negligibly small contribution from $3s$ and $3p$ orbitals for these values of U .

The TDOS of Co_2MnGe in the presence of U are shown in Fig. 9(a). This figure shows that the spin-up channel of Co_2MnGe is metallic for all values of U and down spin channel is semiconducting. As the value of U is increased from 2 to 4 eV, there is broadening of the band gap in the spin-dn channel. The band gap is found to increase from ~ 1.0 eV at $U = 2$ eV to ~ 1.4 eV at $U = 4$ eV. We have not observed any significant

shifting in the TDOS for both spin channels. Thus the on-site Coulomb interactions are not playing a significant effect on this compound, which is also evident from the calculations of magnetic moments. It is clear from PDOS of Co atom shown in Fig. 9(b) that at E_F , the t_{2g} and e_g states contribute same for both values of U . Increasing value of U is not going to affect the PDOS of Co atom. The PDOS of Mn atom (Fig. 9(c)) also shows no difference in the DOS at E_F for these two values of U . Fig. 9(d) shows that contribution from $3s$ and $3p$ states to the TDOS is negligibly small and also not affected by the on-site Coulomb interactions.

From the above results it is clear that the metallic ground state of Fe_2MnAl compound changes directly to the semiconducting ground state when the value of U is increased, whereas ground state of other two Heusler alloys remain half-metallic ferromagnetic. Very few experimental work related to Fe_2MnAl compound is found in the literature. In order to verify our predicted result it is necessary to perform electrical conductivity and neutron diffraction experiments, which directly probe the electronic transport behaviour and the nature of magnetic coupling between the Fe and Mn moments. To the best of our knowledge there are no experimental data on electrical conductivity in the $L2_1$ phase. However Liu et al. [35] have reported resistivity data of the compound when it is in the B_2 phase, which show insulating behaviour at the low temperature. Similarly neutron diffraction experiments on Fe_2MnSi compound are also desirable to know the magnetic moments of the Fe and Mn atoms. These experiments will help in understanding the role of on-site Coulomb interaction among the $3d$ electrons of Fe and Mn by studying the magnitude and directions of the magnetic moments of Fe and Mn atoms in the Fe_2MnSi and Fe_2MnAl compounds.

4. Conclusions

The full-potential linearized augmented-plane wave methods have been employed to study the electronic and magnetic properties of Fe_2MnSi , Fe_2MnAl and Co_2MnGe . The ferromagnetic (FM) solutions without using on-site Coulomb interaction U show the presence of half-metallic FM ground state in Fe_2MnSi however, in Fe_2MnAl the ground state is found to be metallic. The total magnetic moment is contributed by Mn atom with small contribution from Fe atom in both cases. The electronic and magnetic properties of Fe_2MnSi and Fe_2MnAl are affected significantly by U , whereas the almost negligible effect of U is found in Co_2MnGe . The magnetic moment of Fe atom in Fe-based compounds is found to increase with U and for Mn atom its value decreases. In Fe_2MnSi the Fe and Mn moments are coupled ferromagnetically for all values of U , whereas in Fe_2MnAl they coupled antiferromagnetically below $U = 2$ eV and ferromagnetically above it. The study of electronic structures show that in Fe_2MnSi and Co_2MnGe the ground state remains half-metallic ferromagnetic for all values of U , whereas in Fe_2MnAl compound the ground state become semiconducting after $U = 2$ eV. The ferromagnetic coupling between Fe and Mn moments appears to be responsible for this in Fe_2MnAl compound.

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Table 1. Calculated total number of electrons in spin-up ($3d_{up}$) and spin-dn ($3d_{dn}$) channels and partial magnetic moments $m(\mu_B)$ of Fe_2MnSi , Fe_2MnAl and Co_2MnGe with different values of U

Compound	U (eV)	Fe/Co atom			Mn atom		
		$3d_{up}$	$3d_{dn}$	$m(\mu_B)$	$3d_{up}$	$3d_{dn}$	$m(\mu_B)$
Fe_2MnSi	1	3.21	2.92	0.29	3.67	1.26	2.41
	2	3.25	2.89	0.36	3.62	1.32	2.30
	3	3.32	2.82	0.50	3.49	1.44	2.05
	4	3.39	2.74	0.65	3.34	1.59	1.75
	5	3.50	2.63	0.87	3.11	1.82	1.29
Fe_2MnAl	1	2.97	3.10	-0.14	3.55	1.31	2.24
	2	3.03	3.03	0.00	3.41	1.44	1.97
	3	3.11	2.94	0.17	3.24	1.60	1.64
	4	3.20	2.84	0.36	3.03	1.81	1.22
	5	3.29	2.74	0.55	2.80	2.03	0.77
Co_2MnGe	1	4.16	3.09	1.07	3.91	1.11	2.80
	2	4.16	3.08	1.08	3.89	1.13	2.76
	3	4.17	3.06	1.11	3.88	1.15	2.73
	4	4.17	3.05	1.12	3.85	1.17	2.68
	5	4.18	3.03	1.15	3.82	1.21	2.61

Effect of on-site Coulomb interaction (U) on the electronic and magnetic properties of Fe_2MnSi , Fe_2MnAl and

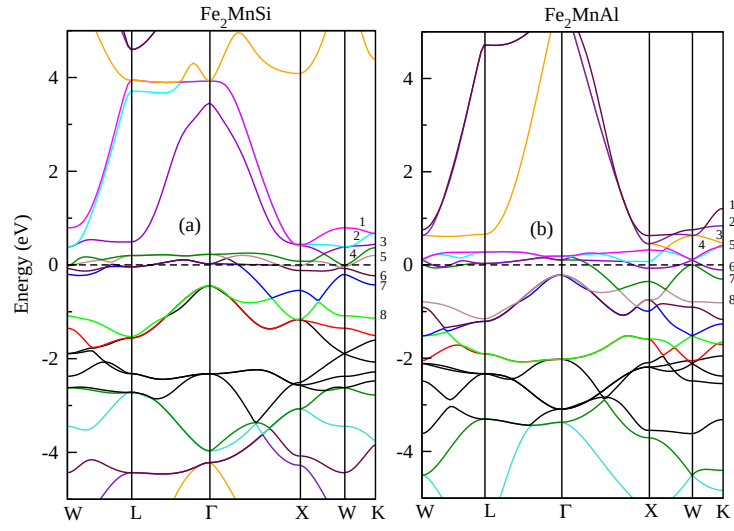


Figure 1. (Color online) Electronic band structures in the paramagnetic phase for (a) Fe_2MnSi and (b) Fe_2MnAl .

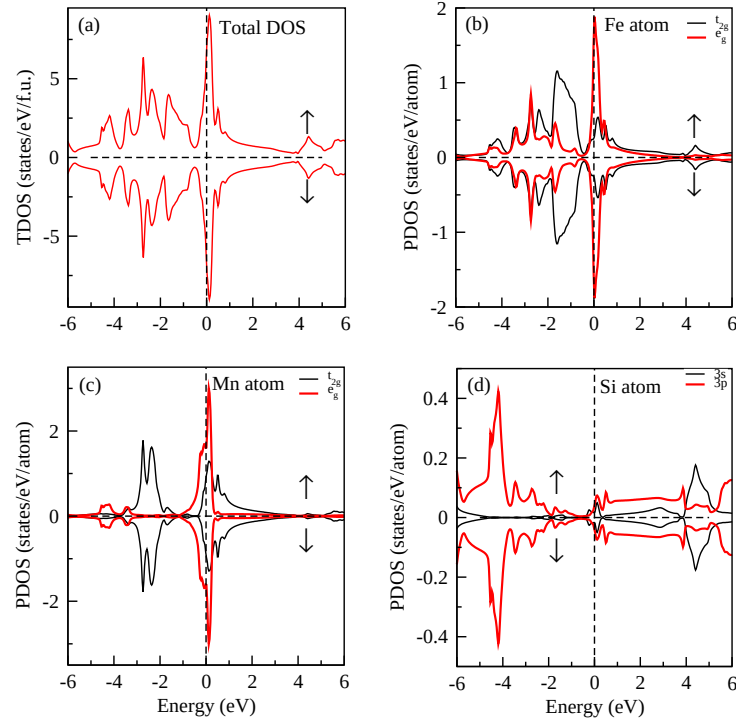


Figure 2. (Color online) Total and partial density of states plots for Fe_2MnSi in the paramagnetic phase. Shown are (a) the TDOS plot, (b) PDOS of Fe atom, (c) PDOS of Mn atom and (d) PDOS of Si atom.

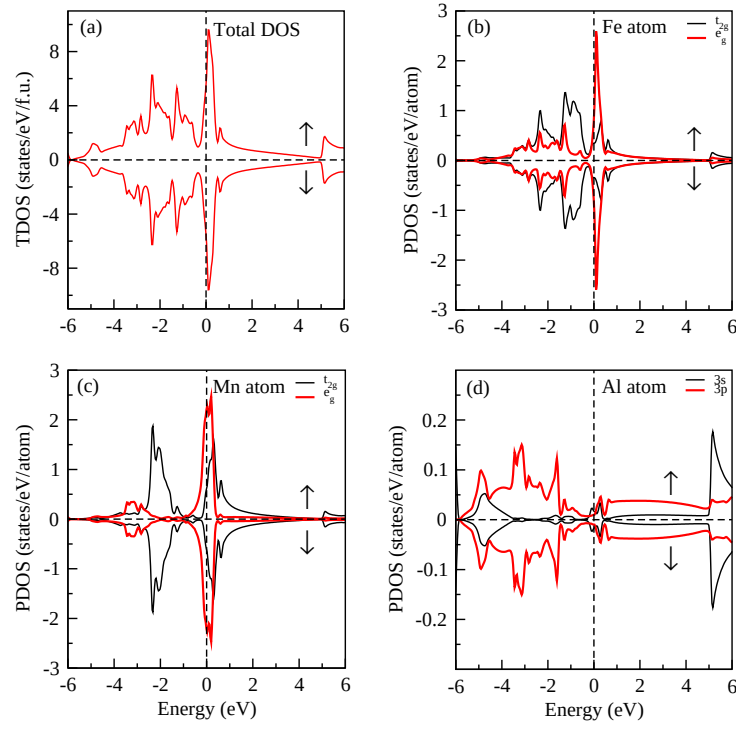


Figure 3. (Color online) Total and partial density of states plots for Fe_2MnAl in the paramagnetic phase. Shown are (a) the TDOS plot, (b) PDOS of Fe atom, (c) PDOS of Mn atom and (d) PDOS of Al atom.

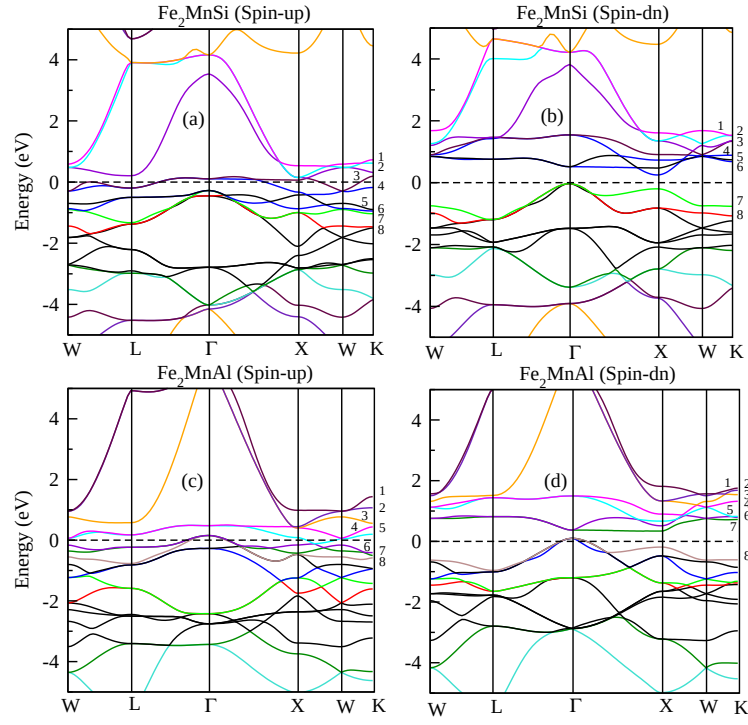


Figure 4. (Color online) Electronic band structures in the ferromagnetic phase (a and b) for spin-up and spin-dn channels of Fe_2MnSi and (c and d) for spin-up and spin-dn channels of Fe_2MnAl .

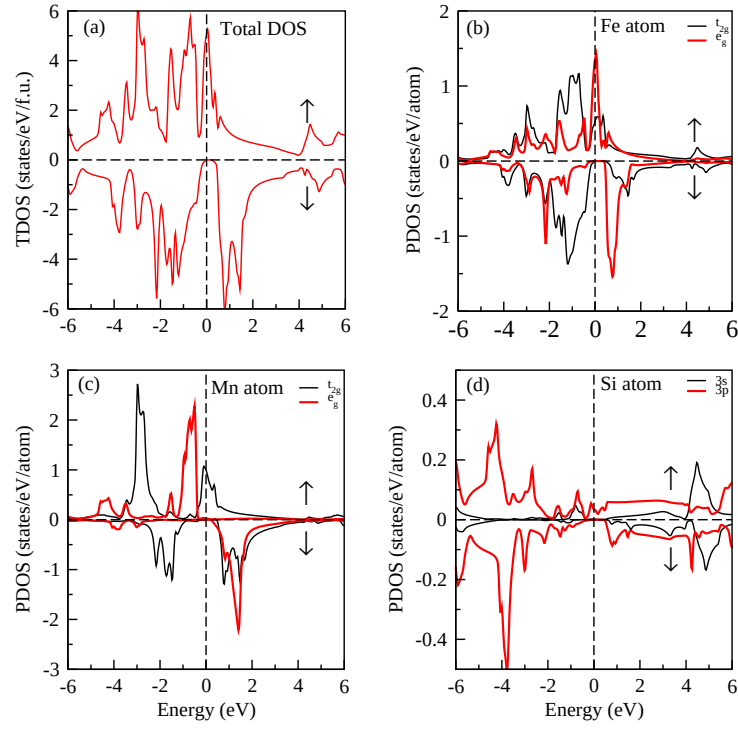


Figure 5. (Color online) Total and partial density of states plots for Fe_2MnSi in the ferromagnetic phase. Shown are (a) the TDOS plot, (b) PDOS of Fe atom, (c) PDOS of Mn atom and (d) PDOS of Si atom.

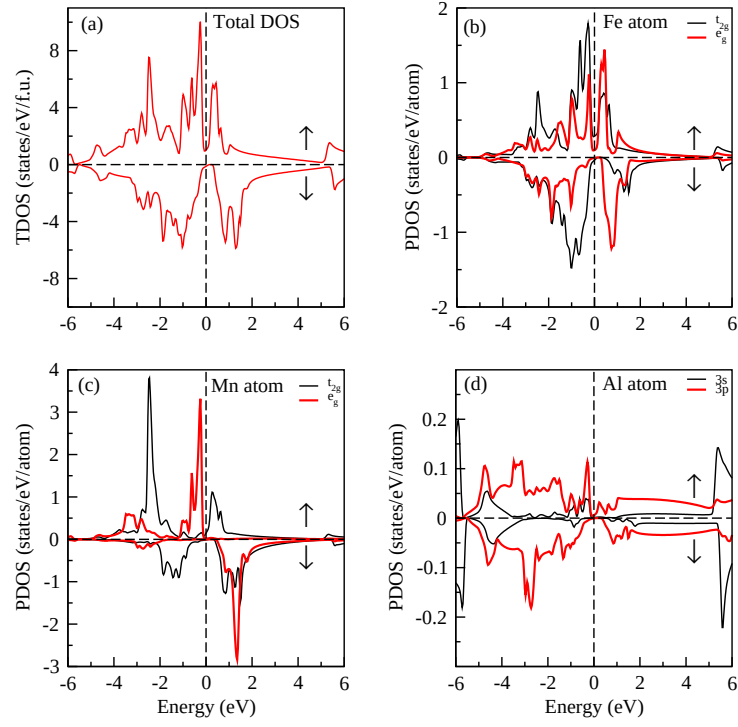


Figure 6. (Color online) Total and partial density of states plots for Fe_2MnAl in the ferromagnetic phase. Shown are (a) the TDOS plot, (b) PDOS of Fe atom, (c) PDOS of Mn atom and (d) PDOS of Al atom.

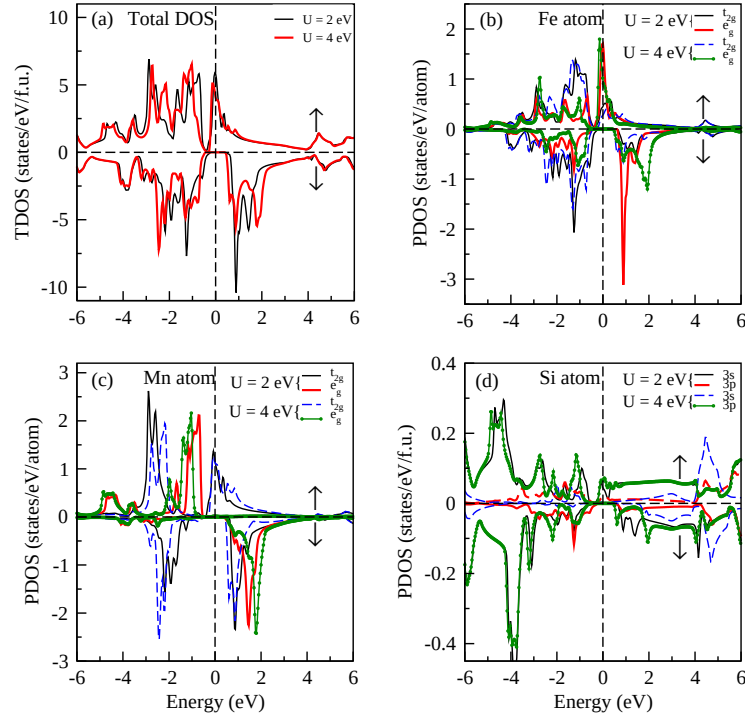


Figure 7. (Color online) Total and partial density of states plots for Fe_2MnSi in the ferromagnetic phase in the presence of U . Shown are (a) the TDOS plot, (b) PDOS of Fe atom, (c) PDOS of Mn atom and (d) PDOS of Si atom.

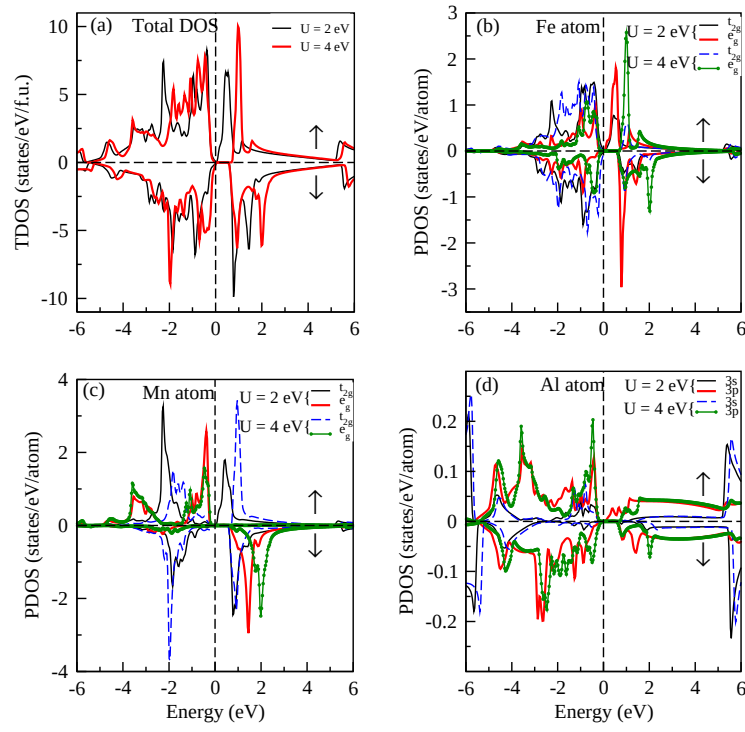


Figure 8. (Color online) Total and partial density of states plots for Fe_2MnAl in the ferromagnetic phase in the presence of U . Shown are (a) the TDOS plot, (b) PDOS of Fe atom, (c) PDOS of Mn atom and (d) PDOS of Al atom.

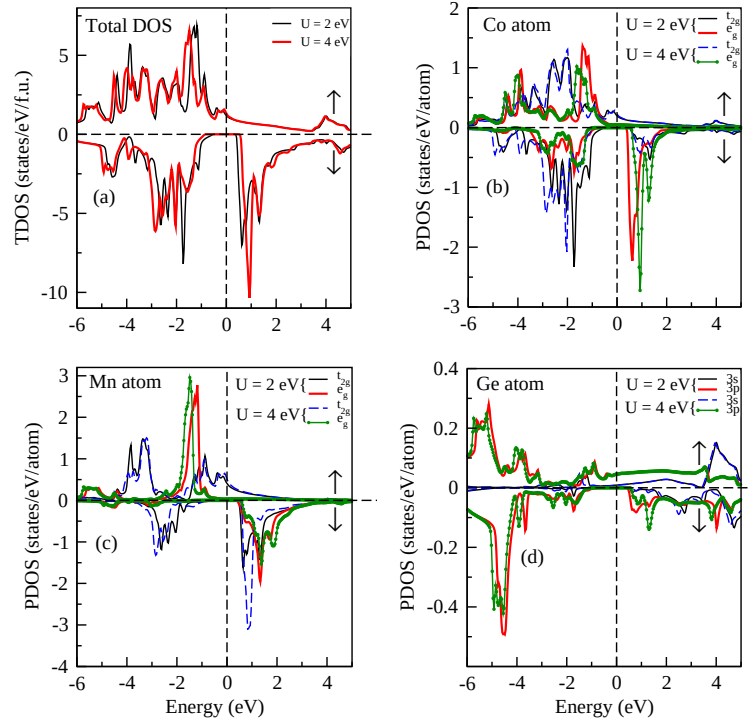


Figure 9. (Color online) Total and partial density of states plots for Co_2MnGe in the ferromagnetic phase in the presence of U . Shown are (a) the TDOS plot, (b) PDOS of Co atom, (c) PDOS of Mn atom and (d) PDOS of Ge atom.